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GENERAL DESCRIPTION

OB2203 is a highly integrated Quasi-Resonant (QR) controller optimized for high performance offline flyback converter applications.

At normal load condition, it operates in QR mode with minimum drain voltage switching. To meet the CISPR-22 EMI starting at 150KHz, the maximum switching frequency is internally limited to 130KHz. It operates in PFM mode for high power conversion efficiency at light load condition. When the loading is very small, the IC operates in 'Extended Burst Mode' to minimize the switching loss. As a result, lower standby power consumption and higher conversion efficiency is achieved.

A built-in P-channel MOSFET and its control are integrated to automatically turn on or off PFC stage according to the load conditions. When used with OB6563 (On-Bright's PFC controller), the standby power consumption of less than 400mW can be achieved in typical 150W SMPS.

OB2203 offers comprehensive protection coverage including Cycle-by-Cycle Current Limiting(OCP), VCC Under Voltage Lockout(UVLO), Over Voltage Protection(OVP), VCC Clamp, Gate Clamp, Over Load Protection(OLP), On-chip Thermal Shutdown, Programmable Soft Start, and External Latch Triggering, Max On-time Limit, etc.

OB2203 is offered in SOP-8 and DIP-8 packages.

FEATURES

- Multi-Mode Operation
- Quasi-Resonant Operation at Normal Loading
- Pulse Frequency Modulation (PFM) Operation at Light Load
- Burst Mode at No Load
- Direct Control of the Power Supply of PFC Controller for Improved Standby Power at No/Light Load
- 40KHz Minimum Frequency Limit at QR Mode
- 130KHz Maximum Frequency Limit
- Internal Minimum T_off for Ringing Suppression
- 45us Maximum On Time Limit
- Adaptive Slope Compensation
- Internal Leading Edge Blanking
- Programmable Soft-start
- External Latch Triggering
- Internal Temperature Shutdown
- 1A Peak Current Sink/Source Capability
- Programmable Over Voltage Protection (OVP)

APPLICATIONS

Offline AC/DC flyback converter for

- Power Adaptor and Open-frame SMPS
- LCD Monitor/TV/PC/Set-Top Box Power Supplies
- NB/DVD/Portable DVD Power Supplies



TYPICAL APPLICATION



GENERAL INFORMATION

Pin Configuration

The pin map of OB2203 in DIP8 and SOP8 package is shown as below.



Ordering Information

Part Number	Description
OB2203AP	8 Pin DIP, Pb free in Tube
OB2203CP	8 Pin SOP, Pb free in Tube
OB2203CPA	8 Pin SOP, Pb free in T&R

Note: All Devices are offered in Pb-free Package if not otherwise noted.

Package Dissipation Rating

Package	RθJA (°C/W)
DIP8	90
SOP8	150

Absolute Maximum Ratings

Parameter	Value
VCC Zener Clamp Voltage	31 V
VCC Clamp Continuous	10 mA
Current	
SS Input Voltage	-0.3 to 7V
FB Input Voltage	-0.3 to 7V
CS Input Voltage	-0.3 to 7V
DEM Input Voltage	-0.3 to 7V
Min/Max Operating Junction	-20 to 150 °C
Temperature T _J	
Min/Max Storage Temperature	-55 to 150 °C
T _{stg}	
Lead Temperature (Soldering,	260 °C
10secs)	

Note: Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute maximum-rated conditions for extended periods may affect device reliability.





Marking Information







TERMINAL ASSIGNMENTS

Pin Num	Pin Name	I/O	Description
1	SS	I/O	Soft-start programming pin. Program the soft-start rate with a capacitor to
			ground. After soft-start, the pin's voltage is clamped at 2V. External latch
			input, latch will be triggered when SS pin voltage higher than 3.8V.
2	FB	I/O	Feedback input pin. PWM duty cycle is determined by voltage level into this
			pin and current-sense signal level at Pin 3. The voltage level at this pin also
			controls the mode of operation in one of the three modes: quasi-resonant
			(QR), pulse frequency modulation mode (PFM) and burst mode (BM).
3	CS	Ι	Current sense input.
4	GND	0	Ground for internal circuitry.
5	GATE	0	Totem-pole gate drive output for power MOSFET.
6	VCC	Р	Chip DC power supply pin.
7	PFCVCC	Р	This pin is a direct connection to the VCC pin via a low impedance switch.
			In standby and during the startup sequence, the switch is open and the
			PFCVCC is shut down. As soon as the auxiliary winding is stabilized,
			PFCVCC connects to the VCC pin and provides power supply to PFC
			controller. It goes down in any fault or at No/Light conditions.
8	DEM	I/O	Input from auxiliary winding for demagnetization timing. Also this pin is
			used for load over voltage protection (OVP).

BLOCK DIAGRAM



RECOMMENDED OPERATING CONDITION

Symbol	Parameter	Min	Max	Unit
VCC	VCC Supply Voltage	12	23	V
T _A	Operating Ambient Temperature	-20	85	°C

ELECTRICAL CHARACTERISTICS

($T_A = 25^{\circ}C$, VCC=16V, if not otherwise noted)

Symbol	Parameter	Test Conditions	Min	Тур	Max	Unit
Supply Voltage (VCC) Section						
I_VCC_Startup	VCC Start up Current	VCC=13.5V, Measure	-	5	15	uA
1	1	current into VCC				
I VCC quiet	Operation Current	FB=3V, CS is floating,	-	2.0	3.0	mA
1	without switching					
I VCC operation	Operation current	FB=3V, Fsw=40KHz, 1nF	-	3.0	4.0	mA
	with switching	load at GATE				
UVLO(ON)	VCC Under Voltage		7.5	8.5	9.5	V
	Lockout Enter					
UVLO(OFF)	VCC Under Voltage		14	15	16	V
	Lockout Exit					
	(Startup)					
OVP(ON)	VCC Over Voltage		29	31	33	V
	Protection Enter					
VCC Clamp	VCC Zener Clamp	I(VCC) = 5 mA	30	32	34	V
	Voltage					
Feedback Input S	ection(FB Pin)	·				
A _{VCS}	PWM Input Gain	$\Delta V_{FB} / \Delta V_{cs}$	-	3.5	-	V/V
V _{FB} Open	FB Open Voltage		4.8	5.3	6.0	V
- 1 <u>D</u> <u>F</u> -						
I _{FB} Short	FB pin short circuit	Short FB pin to GND.	1.0	1.5	-	mA
	current	measure current				
V _{TH} 0D	Zero Duty Cycle FB				0.95	V
·	Threshold Voltage					
V _{TH} PFM H	PFM mode up			1.45		V
	threshold					
V _{TH} PFM L	PFM mode down			1.0		V
	threshold					
V _{TH} BM on	Burst Mode on			1.0		V
	threshold					
V _{TH} BM off	Burst Mode off			0.9		V
	threshold					
V _{TH} PFC GTS	Threshold for PFC to			1.35		V
	go to standby					
V _{TH} _PFC_on	Threshold for PFC to			1.45		V
	leave standby mode					
V _{TH} PL	Power Limiting FB			4.4		V
	Threshold Voltage					
T _D _PL	Power limiting		60	80	120	mSec
	Debounce Time					
Z _{FB} _IN	Input Impedance			4		Kohm
Current Sense Inp	out(CS Pin) Section					
T_blanking	CS Input Leading			350		nSec
	Edge Blanking Time					
V _{TH} OC_0	Internal current	Zero duty cycle	0.43	0.45	0.47	V
	limiting threshold					
V _{TH} OC_60%	Internal current	60% duty cycle		0.80		V
	limiting threshold					
T _D OC	Over Current	CL=1nf at GATE,		100	160	nSec

	Detection and Control					
	Delay					
Demagnetization	Detection Section	Γ			1	I
V _{TH} DEM	Demagnetization comparator threshold		10	75	30	mV
V DEM byot	Hustoresis for DEM					
V _{TH} _DEW_nyst	comparator			20		mV
	Negative clamp					
V _{DEM} clamp(neg)	voltage			-0.7		V
V_{DEM} clamp(pos)	Positive clamp			5.0		X 7
<u> </u>	voltage			5.8		V
T _{supp}	Suppression of the					
	transformer ringing at		1.5	2	2.5	11500
	start of secondary		1.5	2	2.3	usee
	stroke					
T _{OUT}	Timeout after last		4	5	6	usec
	demag transistion		· ·	-	Ŭ	usee
T _{DEM_delay}	Demag propagation			150		nsec
	delay			2.75		X7
	OVP trigger point			3.75		V
I_ovp_plateau	OVP plateau		1.5	2	2.5	11600
	sampling after		1.3	2	2.3	usec
N true OVP	Number of					
	subsequent cycles to			4		Cycle
	be true OVP					Cycle
Soft Start Section						
Iss	Soft start charge		8.0	10	12	uA
	current					
V _{TH} ss over	Soft start over			2.2		V
	threshold voltage					
I _{ss_} clamp_sink	Maximum sink		80	120	200	uA
	current capability					
	when SS is clamped					
V _{SS} _clamp	SS pin high clamp			5.8		V
	voltage					
Timer Section					1	
F_burst	Burst mode switching			22		KHz
E OD alama h	Trequency		117	120	1.4.2	VII-
F_QR_clamp_n	in OP mode		11/	130	145	KHZ
E OR clamp 1	Frequency low clamp		35	40	45	KH2
	in OR mode		55	40	45	KIIZ
Ton max	Maximum on time		30	45	55	11500
Toff max	Maximum off time		30	45	55	usec
G PFM	PFM mode frequency			240		KHz/V
<u></u>	modulation slope					
	versus control voltage					
Thermal Protection)n	1				•
T shutdown	Thermal shutdown		130	140	150	°C
	temperature					
Latch Protection						
V_latch_trigger	Latch trigger threshod	SS pin pull up current		3.8		V

				-		
	voltage at SS pin	should be larger than				
		200uA				
V_latch_release	VCC latch release		5.5	6	6.5	V
	voltage					
Ivdd(latch)	VCC current when	VCC=V_latch_release+1		40		uA
	latch off	V				
PFCVCC section						
Rdson	On-resistance of		10	20	20	0
	PMOS switch		10	20	50	52
T_PFC_GTS	PFC go to standby		100	125	140	m G
	debounce time		100	123	140	1115
T_PFC_ON	PFC ON debounce		4	0	12	mS
	time		4	0	12	1115
Gate Drive Outpu	ıt					
VOL	Output Low Level	Io = 100 mA (sink)			1	V
VOH	Output High Level	Io = 100 mA (source)	7.5			V
VG Clamp	Output Clamp	VCC=20V	15.5	16.5	17.5	V
	Voltage Level					
Τr	Output Rising Time	CL = 1nf		50		nSec
Τf	Output Falling Time	CL = 1nf		20		nSec

CHARACTERIZATION PLOTS

Temperature(C)

OPERATION DESCRIPTION

Quasi-Resonant (QR) converter typically features lower EMI and higher power conversion efficiency compared to conventional hard-switched converter with a fixed switching frequency. OB2203 is a highly integrated QR controller optimized for offline flyback converter applications. The built-in advanced energy saving with high level protection features provide cost effective solutions for energy efficient power supplies.

• Startup Current and Start up Control

Startup current of OB2203 is designed to be very low so that VCC could be charged up above UVLO(exit) threshold level and device starts up quickly. A large value startup resistor can therefore be used to minimize the power loss yet reliable startup in application. For a typical AC/DC adaptor with universal input range design, a 2 M Ω , 1/8 W startup resistor could be used together with a VCC capacitor to provide a fast startup and yet low power dissipation design solution.

• Operating Current

The operating current of OB2203 is as low as 2.3mA. Good efficiency is achieved by the low operating current together with extended burst mode control schemes at No/light conditions.

• Multi-Mode Operation for High Efficiency

OB2203 is a multi-mode QR controller. The controller changes the mode of operation according to FB voltage, which reflects the line and load conditions.

■ Under normal operating conditions (FB>Vth2, Figure 1), the system operates in QR mode. The frequency variation in QR mode is limited to the range of 40KHz ~ 130KHz due to the fact that frequency varies depending on the line voltage and the load conditions. Therefore, the system may actually work in DCM when 130KHz frequency clamping is reached. In contrast, the system may actually work in CCM when 40KHz frequency clamping is reached. System design should be optimized such that the operation frequency is within the range specified at full loading conditions and in universal AC line input range.

■ At light load condition (Vth1<VFB<Vth2, Figure 1), the system operates in PFM (pulse frequency modulation) mode for high power conversion efficiency. In PFM mode, the "ON" time in a switching cycle is fixed and the system modulates

the frequency according to the load conditions. Generally, in flyback converter, the decreasing of loading results in voltage level decreasing at FB pin. The controller monitors the voltage level at FB and control the switching frequency. However, the valley switching characteristic is still preserved in PFM mode. That is, when loading decreases, the system automatically skip more and more valleys and the switching frequency is thus reduced. In such way, a smooth frequency foldback is realized and high power conversion efficiency is achieved.

■ At zero load or very light load conditions (VFB<Vth1), the system operates in On-Bright's proprietary "extended burst mode". In this condition, voltage at FB is below burst mode threshold level, Vth1. The Gate drive output switches only when VCC voltage drops below a preset level or FB input is active to output an on state. Otherwise the gate drive remains at off state to minimize the switching loss thus reduce the standby power consumption to the greatest extend. In extended burst mode, the switching frequency is fixed to 22KHz, in this way, possible audio noise is eliminated.

Figure 1

• Demagnetization Detection

The core reset is detected by monitoring the voltage activity on the auxiliary windings through DEM pin. This voltage features a flyback polarity. A new cycle starts when the power switch is activated. After the on time (determined by the CS voltage and FB), the switch is off and the flyback stroke starts. After the flyback stroke, the drain voltage shows an oscillation with a frequency of approximately $1/2\pi\sqrt{L_pC_d}$, where L_p is the

primary self inductance of the transformer and C_d is the capacitance on the drain node.

Figure 2

The typical detection level is fixed at 75mV at the DEM pin. Demagnetization is recognized by detection of a possible "valley" when the voltage at DEM is below 75mV in falling edge. DEM detection is suppressed during the first T_{supp} time (typical value of 2us). This suppression is necessary in applications where the transformer has a large leakage inductance and at low output voltages or start-up.

• Current Sensing and Leading Edge Blanking

Cycle-by-Cycle current limiting is offered in OB2203 current mode control. The switch current is detected by a sense resistor into the CS pin. An internal leading edge blanking circuit chops off the sense voltage spike at initial MOSFET on state due to snubber diode reverse recovery so that the external RC filtering on sense input is no longer needed. The current limit comparator is disabled and cannot turn off the external MOSFET during the blanking period. The PWM duty cycle is determined by the current sense input voltage and the FB input voltage.

• Adaptive Slope Compensation at Large Load

The slop compensation to ensure system stable operation is active only at large load condition. At large load conditions (such as startup), the switching frequency can be low clamped to 40KHz and the system will actually work in CCM mode. To prevent the possible unstable operation and the sub-harmonic oscillation, an internal synchronized slope compensation is added to the current loop. The internal synchronized slope compensation is disabled at normal or light load, in such condition, the system will work in either QR or DCM mode.

Quasi-Resonant Flyback PWM Controller

• Maximum and Minimum On-Time

The minimum on-time of the system is determined by the LEB time (typical 350ns). The IC limits the on-time to a maximum time of 45us.

• Ringing Suppression Timer

A ringing suppression timer is implemented. In normal operation, the ringing suppression timer starts when CS reaches the feedback voltage FB, the gate drive GATE is set to low. During the ringing suppression time, gate drive GATE remains in low state and cannot turn power switch on gain. The ringing suppression is necessary in applications where the transformer has a large leakage inductance, particularly at low output voltages or startup. In OB2203, the ringing suppression timer is set to 2us internally.

• PFC VCC power on/off control

In medium to large power applications, PFC preconverter is required and PFC controller is powered by PWM auxiliary power supply. PFCVCC pin is directly connected to VCC pin by an internal low impedance power switching, thus no external components are needed. PFCVCC is shut down in any of the following conditions: any fault condition, No load/light load condition, soft start sequence and VCC voltage less than 12V.

• Maximum and Minimum Frequency Clamp in QR operation

According to the QR operation principle, the switching frequency is inversely proportional to the output power. Therefore, when the output power decreases, the switching frequency can become rather high without limiting. To meet the CISPR-22 EMI limit starting at 150KHz, the maximum switching frequency in OB2203 is internally limited to 130KHz. In addition to up clamping, the switching frequency is also low clamped to 40KHz in QR mode.

• On chip Thermal shutdown

OB2203 provides an on chip thermal shutdown. The IC will stop switching when the junction temperature exceeds the thermal shutdown temperature, typically 140 °C. The IC resumes normal operation when the junction temperature decreased by 20 °C

• External latch trip point

By externally forcing a level on pin SS (e.g., with a signal coming from a temperature sensor) greater than 3.8V, OB2203 can be permanently latched-off. To resume normal operation, VCC voltage should

go below 6V, which implies to unplug the SMPS form the mains.

• OCP compensation for CCM/DCM

A proprietary OCP compensation is provided for better OCP performance in the universal input range. Comparing to conventional OCP compensation where the gate delay is compensated, more sophisticated compensation is provided to also compensate the OCP at different line voltage since the switching frequency varies with line voltage. In this way, a more accurate OCP is achieved.

• Over voltage protection (OVP)

An over voltage protection (OVP) is implemented by sensing the auxiliary winding voltage at DEM pin during the flyback phase. The auxiliary winding voltage is a well-defined replica of the output voltage. The OVP works by sampling the plateau voltage at DEM pin during the flyback phase. A 2 us internal delay (plateau sampling) guarantees a clean plateau, provided that the leakage inductance ringing has been fully damped.

If the sampled plateau voltage exceeds the OVP trip level (3.75V), an internal counter starts counting subsequent OVP events. If OVP events are detected in successive 4 cycles, the controller assumes a true OVP and it enters a latch off mode and stops all switching operations. The counter has been added to prevent incorrect OVP detection which might occur during ESD or lightning events. If the output voltage exceeds the OVP trip level less than 4 successive cycles, the internal counter will be cleared and no fault is asserted.

Quasi-Resonant Flyback PWM Controller

When over load (for example, short circuit) occurs, the feedback current is below minimum value and a fault is detected. If this fault is present for more than 80ms, the controller enters an auto-recovery soft burst mode. All pulses are stopped, VCC will drops below UVLO and the controller will try to restart with the power on soft start. The SMPS enters the burst sequence and it resumes operation once the fault disappears.

• Programmable Soft Start

OB2203 features a programmable soft start to soften the constraints in the power supply during the startup. It is activated during the power on sequence. As soon as VCC reaches UVLO(OFF), an internal trimmed 10 uA current is sourced from SS pin and charges the external programming capacitor, the peak current is then gradually increased from zero. When SS pin reaches 2.2V, soft start process is over.

Figure 4

During the soft start process, there is a low frequency (40KHz) clamping to avoid the system switching frequency going too low. Every restart attempt is followed by soft start sequence.

• Gate Drive

The Gate pin is connected to the gate of an external MOSFET for power switch control. Too weak the gate drive results in higher conduction and switch loss of MOSFET while too strong gate drive output compromises the EMI.

Good tradeoff is achieved through the built-in totem pole gate drive design with right output strength and dead time control. The low idle loss and good EMI system design is easier to achieve with this dedicated control scheme. An internal 15V clamp is added for MOSFET gate protection at high VCC voltage.

Overload Operation

PACKAGE MECHANICAL DATA

8-Pin Plastic DIP

DIP8 PACKAGE OUTLINE DIMENSIONS

Symbol	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
А	3.710	4.310	0.146	0.170	
A1	0.500		0.020		
A2	3.200	3.600	0.126	0.142	
В	0.350	0.650	0.014	0.026	
B1	1.524	(BSC)	0.060 (BSC)		
С	0.200	0.360	0.008	0.014	
D	9.000	9.500	0.354	0.374	
E	6.200	6.600	0.244	0.260	
E1	7.320	7.920	0.288	0.312	
e	2.540	(BSC)	0.100 (BSC)		
L	3.000	3.600	0.118	0.142	
E2	8.200	9.000	0.323	0.354	

8-Pin Plastic SOP

SOP8 PACKAGE OUTLINE DIMENSIONS

Symbol	Dimensions I	n Millimeters	Dimensions In Inches		
Symbol	Min	Max	Min	Max	
А	1.350	1.750	0.053	0.069	
A1	0.100	0.250	0.004	0.010	
A2	1.300	1.550	0.051	0.061	
b	0.330	0.510	0.013	0.020	
с	0.170	0.250	0.006	0.010	
D	4.700	5.150	0.185	0.203	
Е	3.800	4.000	0.150	0.157	
E1	5.800	6.200	0.228	0.244	
e	1.270	(BSC)	0.050 (BSC)		
L	0.400	1.270	0.016	0.050	
θ	0°	8°	0°	8°	